

SCHOTTKY BARRIER RECTIFIER

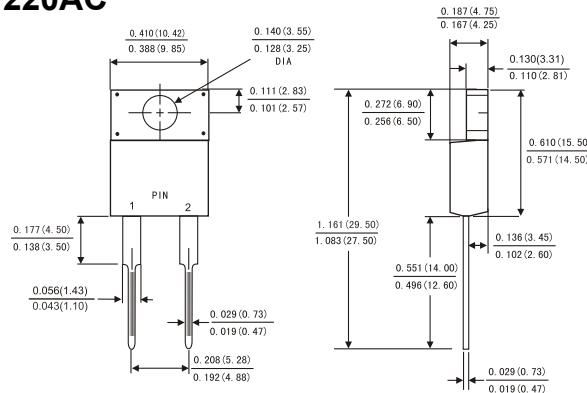
FEATURES

- ◇ Metal-semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC ITO-220AC, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Weight: 0.08ounces, 2.24 grams
- ◇ Mounting position: Any

ITO - 220AC



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

	Symbols	MBRF 820	MBRF 830	MBRF 840	MBRF 850	MBRF 860	MBRF 880	MBRF 8100	MBRF 8150	MBRF 8200	Units				
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	Volts				
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	Volts				
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	Volts				
Maximum average forward rectified current (see Fig. 1)	I _(AV)	8.0								Amps					
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	150.0								Amps					
Maximum instantaneous forward voltage at 8.0 A(Notes 1)	V _F	0.60		0.75		0.85		0.90		0.95					
Maximum instantaneous reverse current at rated DC blocking voltage(Notes 1)	T _A =25°C T _A =125°C	I _R	0.2						mA						
			15		50										
Typical thermal resistance (Notes 2)	R _{θJC}	2.5								°C/W					
Operating junction temperature range	T _J	-65 to +150								°C					
Storage temperature range	T _{STG}	-65 to +150								°C					

NOTE: 1. Pulse test: 300us pulse width, 1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient

RATINGS AND CHARACTERISTIC CURVES

MBRF820 --- MBRF8200

FIG.1-FORWARD CURRENT DERATING CURVE

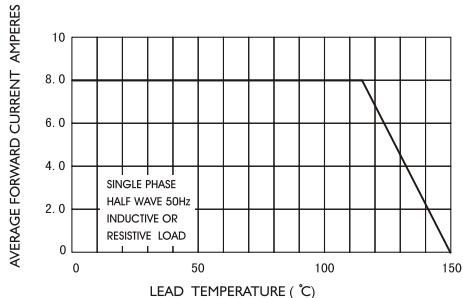


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

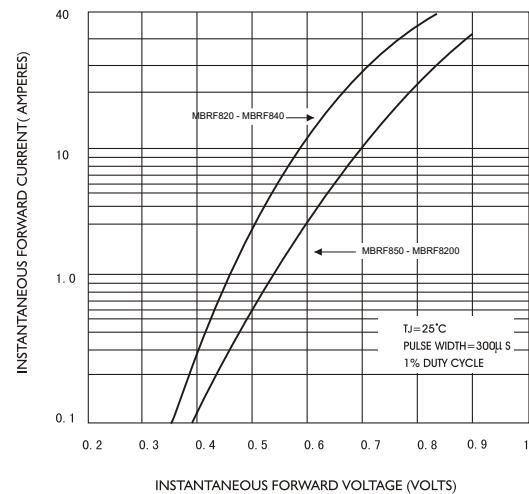


FIG.4-TYPICAL JUNCTION CAPACITANCE

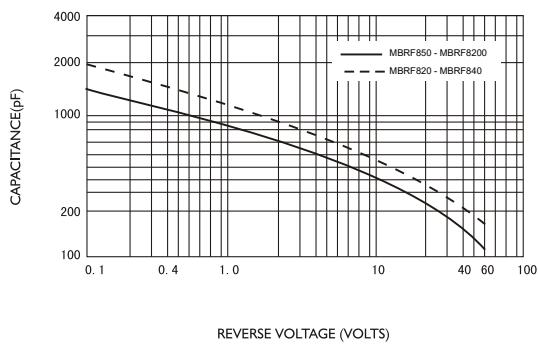


FIG.3-TYPICAL REVERSE CHARACTERISTICS

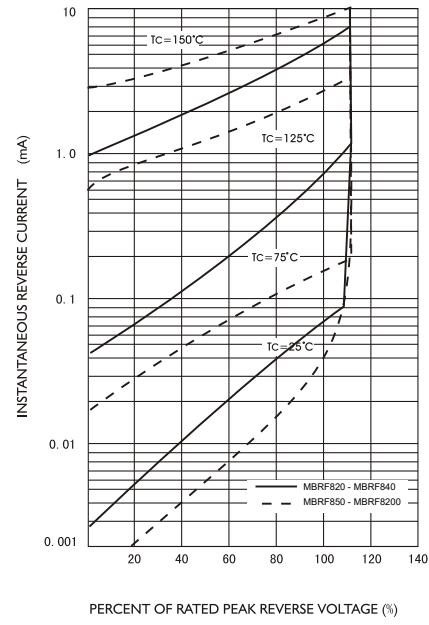


FIG.5-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

